

# RJK1002DPP-E0

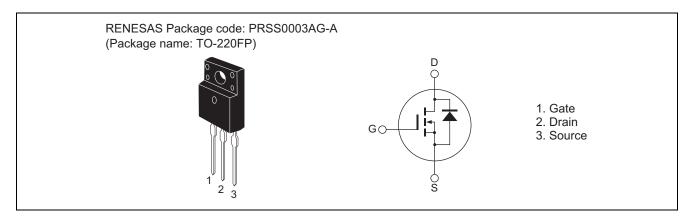
N-Channel MOS FET 100 V, 70 A, 7.6 m $\Omega$ 

R07DS0626EJ0200 Rev.2.00 Oct 17, 2012

#### **Features**

- High speed switching
- Low drive current
- Low on-resistance  $R_{DS(on)} = 6.0 \text{ m}\Omega$  typ. (at  $V_{GS} = 10 \text{ V}$ )
- Package TO-220FP

#### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	100	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	70	A
Drain peak current	I <sub>D (pulse)</sub> Note1	210	А
Body-drain diode reverse drain current	I <sub>DR</sub>	70	Α
Avalanche current	I <sub>AP</sub> Note2	35	А
Avalanche energy	E <sub>AS</sub> Note2	123	mJ
Channel dissipation	Pch Note3	30	W
Channel to case thermal impedance	θch-c	4.17	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

- 2. Value at L = 100  $\mu$ H, Tch = 25°C, Rg  $\geq$  50  $\Omega$ ,
- 3.  $Tc = 25^{\circ}C$

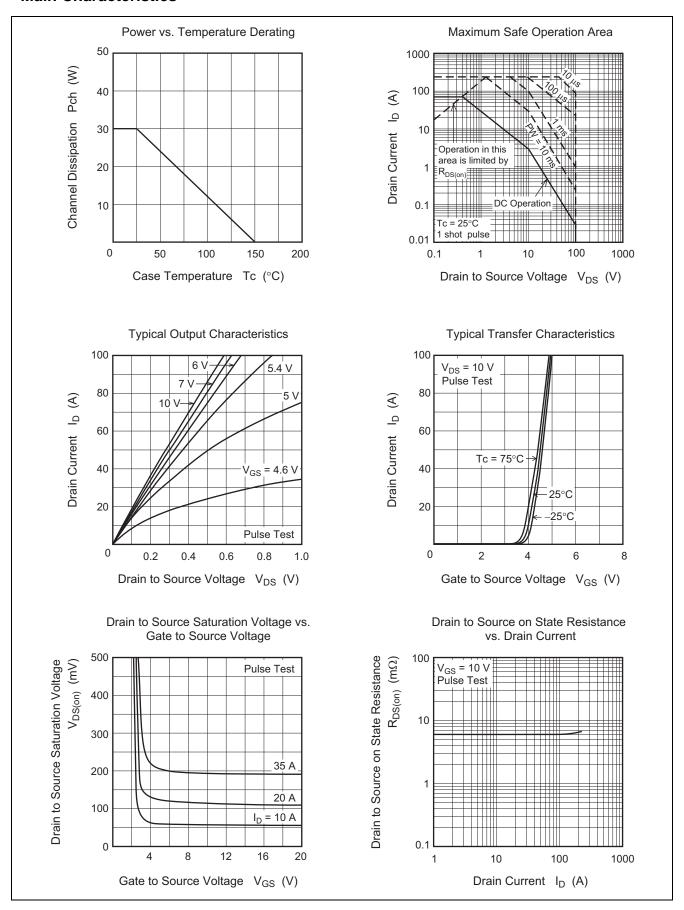
## **Electrical Characteristics**

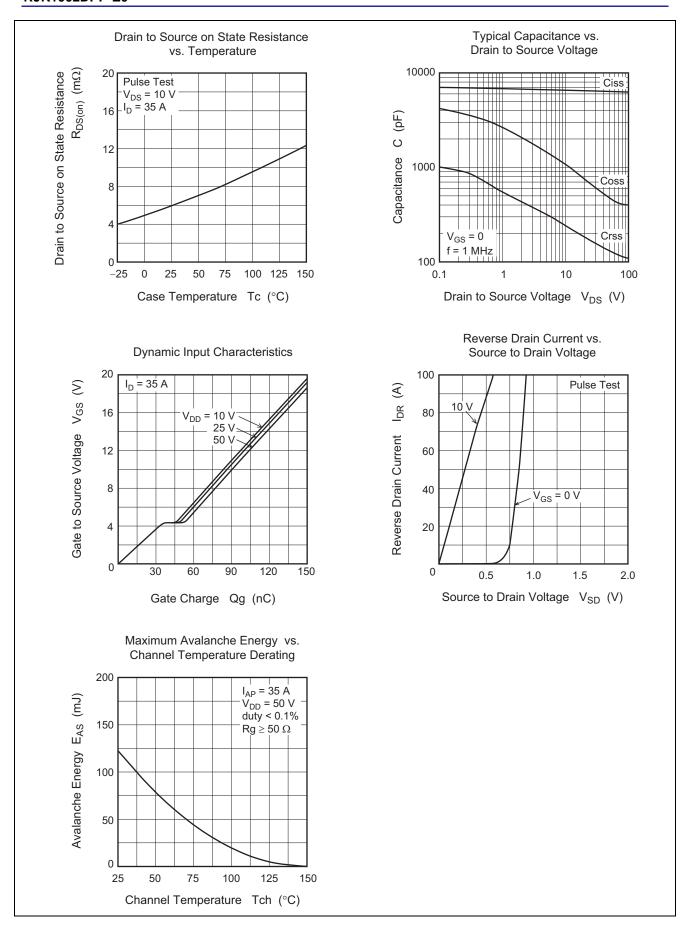
 $(Ta = 25^{\circ}C)$ 

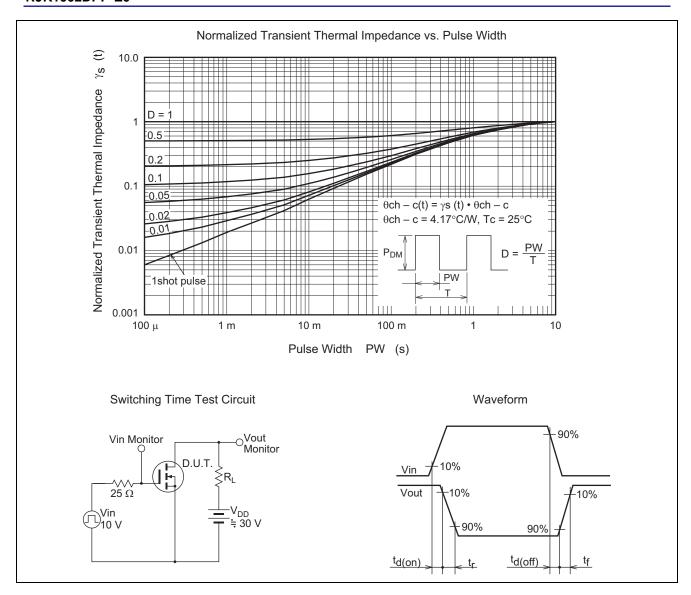
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	100	_	_	V	$I_D = 10 \text{mA}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 100 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	2.0	_	4.0	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R <sub>DS(on)</sub>		6.0	7.6	mΩ	$I_D = 35 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance						
Forward transfer admittance	y <sub>fs</sub>		135	_	S	$I_D = 35 \text{ A}, V_D = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss		6450	_	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss	_	1000	_	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	240	_	pF	
Gate Resistance	Rg	_	1.5	_	Ω	
Total gate charge	Qg	_	94	_	nC	$V_{DD}$ = 50 V $V_{GS}$ = 10 V, $I_{D}$ = 35 A
Gate to source charge	Qgs	_	33	_	nC	
Gate to drain charge	Qgd	_	19	_	nC	
Turn-on delay time	t <sub>d(on)</sub>		40	_	ns	V <sub>GS</sub> = 10 V
Rise time	t <sub>r</sub>		13	_	ns	$\begin{split} I_D &= 35 \text{ A} \\ V_{DD} &\cong 30 \text{ V} \\ Rg &= 4.7  \Omega \end{split}$
Turn-off delay time	t <sub>d(off)</sub>		80	_	ns	
Fall time	t <sub>f</sub>	_	13	_	ns	
Body-drain diode forward voltage	$V_{DF}$	_	0.85	1.5	V	$I_F = 70 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	65	_	ns	$I_F = 70 \text{ A}, V_{GS} = 0$
						$di_F/dt = 100 A/\mu s$

Notes: 4. Pulse test

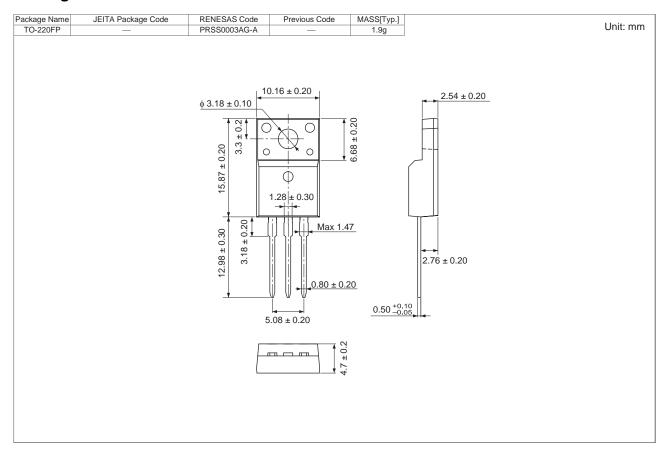
### **Main Characteristics**







## **Package Dimensions**



# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJK1002DPP-E0-T2	50 pcs	Magazine (Tube)

Note: The symbol of 2nd "-" is occasionally presented as "#".

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